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November 2006

FAIRCHILD SEMICONDUCTOR®

FXL2TD245 Low Voltage Dual Supply 2-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-STATE Outputs and Independent Direction Controls

General Description

The FXL2TD245 is a configurable dual-voltage-supply translator designed for both uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6V to as low as 1.1V. The A Port tracks the V_{CCA} level, and the B Port tracks the V_{CCB} level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.

The device remains in 3-STATE until both V_{CC}s reach active levels allowing either V_{CC} to be powered-up first. Internal power down control circuits place the device in 3-STATE if either V_{CC} is removed.

The Transmit/Receive inputs independently determine the direction of data through each of the two bits. The \overline{OE} input, when HIGH, disables both the A and B Ports by placing them in a 3-STATE condition. The FXL2TD245 is designed so that the control pins (T/ \overline{R} and \overline{OE}) are supplied by V_{CCA}.

Features

- Bi-directional interface between any 2 levels from 1.1V to 3.6V
- Fully configurable: Inputs track V_{CC} level
- Non-preferential power-up sequencing; either V_{CC} may be powered-up first
- Outputs remain in 3-STATE until active V_{CC} level is reached
- Outputs switch to 3-STATE if either V_{CC} is at GND
- Power-off protection
- Control inputs (T/R_n, OE) levels are referenced to V_{CCA} voltage
- Packaged in the Chipscale MicroPak10 (1.6mm x 2.1mm)
- ESD protections exceeds:
 - 4kV HBM ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 8kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 1kV CDM ESD (per ESD STM 5.3)
 - 200V MM ESD (per JESD22-A115 & ESD STM5.2)

Ordering Information

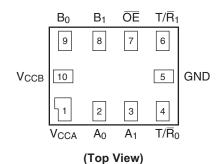
Order Number	Package Number	Pb-Free	Package Description
FXL2TD245L10X	MAC010A	Yes	10-Lead MicroPak, 1.6mm x 2.1mm

Pb-Free package per JEDEC J-STD-020B.

3-STATE XL2TD245 **Outputs and Independent Direction Controls** Low Voltage Dual Supply 2-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and

Functional Diagram V_{CCA} V_{CCB} \overline{OE} A_0 T/\overline{R}_0 T/\overline{R}_0 A_1 D_0 A_1 D_0 A_1 D_0 A_1 D_0 A_1 D_0 A_1 B_1 T/\overline{R}_1 D_0 A_1 D_0 A_1 A

Connection Diagram



Pin Assignment

Pin Number	Terminal Name
1	V _{CCA}
2	V _{CCA}
3	A ₁
4	T/R ₀
5	GND
6	T/R ₁
7	ŌĒ
8	B ₁
9	B ₀
10	V _{CCB}

Pin Descriptions

Pin Names	Description
ŌĒ	Output Enable Input
T/R _n	Transmit/Receive Inputs
A _n	Side A Inputs or 3-STATE Outputs
B _n	Side B Inputs or 3-STATE Outputs
V _{CCA}	Side A Power Supply
V _{CCB}	Side B Power Supply

Truth Table

Inputs			
ŌE	T/R ₀	T/R ₁	Outputs
L	L	Х	B ₀ Data to A ₀ Output
L	Н	Х	A ₀ Data to B ₀ Output
L	Х	L	B ₁ Data to A ₁ Output
L	Х	Н	A ₁ Data to B ₁ Output
Н	Х	Х	3-STATE

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

Power-Up/Power-Down Sequencing

FXL translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0 volts, outputs are in a HIGH-Impedance state. The control inputs (T/ \overline{R}_n and \overline{OE}) are designed to track the V_{CCA} supply. A pull-up resistor tying \overline{OE} to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/power-down. The size of the pull-up resistor is based upon the current-sinking capability of the \overline{OE} driver.

The recommended power-up sequence is the following:

- 1. Apply power to either V_{CC} .
- 2. Apply power to the T/\overline{R}_n inputs (Logic HIGH for A-to-B operation; Logic LOW for B-to-A operation) and to the respective data inputs (A Port or B Port). This may occur at the same time as Step 1.
- 3. Apply power to other V_{CC} .
- 4. Drive the \overline{OE} input LOW to enable the device.

The recommended power-down sequence is the follow-ing:

- 1. Drive $\overline{\text{OE}}$ input HIGH to disable the device.
- 2. Remove power from either V_{CC} .
- 3. Remove power from other $\mathsf{V}_{\mathsf{CC}}.$

Absolute Maximum Ratings

The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Symbol	Parameter	Rating
V _{CCA} , V _{CCB}	Supply Voltage	-0.5V to +4.6V
VI	DC Input Voltage I/O Port A I/O Port B Control Inputs (T/R _n , OE)	-0.5V to +4.6V -0.5V to +4.6V -0.5V to +4.6V
Vo	Output Voltage ⁽¹⁾ Outputs 3-STATE Outputs Active (A _n) Outputs Active (B _n)	-0.5V to +4.6V -0.5V to V _{CCA} + 0.5V -0.5V to V _{CCB} + 0.5V
I _{IK}	DC Input Diode Current @ V _I < 0V	-50mA
Іок	DC Output Diode Current @ $V_O < 0V$ $V_O > V_{CC}$	-50mA +50mA
I _{OH} / I _{OL}	DC Output Source/Sink Current	-50mA / +50mA
I _{CC}	DC V _{CC} or Ground Current per Supply Pin	±100mA
T _{STG}	Storage Temperature Range	-65°C to +150°C

Recommended Operating Conditions⁽²⁾

Symbol	Parameter	Rating
$V_{\rm CCA}$ or $V_{\rm CCB}$	Power Supply Operating	1.1V to 3.6V
	Input Voltage	
	Port A	0.0V to 3.6V
	Port B	0.0V to 3.6V
	Control Inputs $(T/\overline{R}_n, \overline{OE})$	0.0V to V _{CCA}
	Output Current in I _{OH} /I _{OL} with V _{CC @}	
	3.0V to 3.6V	±24mA
	2.3V to 2.7V	±18mA
	1.65V to 1.95V	±6mA
	1.4V to 1.65V	±2mA
	1.1V to 1.4V	±0.5mA
T _A	Free Air Operating Temperature	-40°C to +85°C
$\Delta t/\Delta V$	Maximum Input Edge Rate $V_{CCA/B} = 1.1V$ to 3.6V	10ns/V

Notes:

1. I_O Absolute Maximum Rating must be observed.

2. All unused inputs and input/output pins must be held at $\rm V_{\rm CCI}$ or GND.

Symbol	Parameter	Conditions	V _{CCI} (V)	V _{CCO} (V)	Min.	Max.	Units
VIH	High Level Input	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6	2.0		V
	Voltage ⁽³⁾		2.3–2.7		1.6		
			1.65–2.3		0.65 x V _{CCI}		
			1.4–1.65	1	0.65 x V _{CCI}		
			1.1–1.4	1	0.9 x V _{CCI}		
		Control Pins \overline{OE} , T/ \overline{R}_n	2.7–3.6	1.1–3.6	2.0		
		(Referenced to V _{CCA})	2.3–2.7	1	1.6		
			1.65–2.3	1	0.65 x V _{CCA}		
			1.4–1.65		0.65 x V _{CCA}		
			1.1–1.4		0.9 x V _{CCA}		
V _{IL}	Low Level Input	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6		0.8	V
	Voltage ⁽³⁾		2.3–2.7			0.7	
			1.65–2.3			0.35 x V _{CCI}	
			1.4–1.65	-		0.35 x V _{CCI}	
			1.1–1.4			0.1 x V _{CCI}	
		Control Pins \overline{OE} , T/ \overline{R}_n	2.7–3.6	1.1–3.6		0.8	
		(Referenced to V_{CCA})	2.3–2.7			0.7	
			1.65–2.3			0.35 x V _{CCA}	
			1.4–1.65			0.35 x V _{CCA}	
			1.1–1.4	-		0.1 x V _{CCA}	
V _{OH}	High Level Output	I _{OH} = -100μA	1.1–3.6	1.1–3.6	V _{CC0} -0.2		V
	Voltage ⁽⁴⁾	I _{OH} = -12mA	2.7	2.7	2.2		
		I _{OH} = -18mA	3.0	3.0	2.4		
		I _{OH} = -24mA	3.0	3.0	2.2		
		I _{OH} = -6mA	2.3	2.3	2.0		
		I _{OH} = -12mA	2.3	2.3	1.8		
		I _{OH} = -18mA	2.3	2.3	1.7		
		I _{OH} = -6mA	1.65	1.65	1.25		
		$I_{OH} = -2mA$	1.4	1.4	1.05		
		I _{OH} = -0.5mA	1.1	1.1	0.75 x V _{CC0}		
V _{OL}	Low Level Output	I _{OL} = 100μA	1.1–3.6	1.1- 3.6		0.2	V
	Voltage ⁽⁴⁾	$I_{OL} = 12mA$	2.7	2.7		0.4	
		I _{OL} = 18mA	3.0	3.0		0.4	
		$I_{OL} = 24 \text{mA}$	3.0	3.0		0.55	
		I _{OL} =12mA	2.3	2.3		0.4	
		$I_{OL} = 18 \text{mA}$	2.3	2.3		0.6	
		$I_{OL} = 6mA$	1.65	1.65		0.3	1
		$I_{OL} = 2mA$	1.4	1.4		0.35	
		$I_{OL} = 0.5 \text{mA}$	1.1	1.1		0.3 x V _{CC0}	
I	Input Leakage Current Control	$V_{I} = V_{CCA}$ or GND	1.1–3.6	3.6		±1.0	μA

FXL2TD245 Low Voltage Dual Supply 2-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-STATE Outputs and Independent Direction Controls

Symbol	Parameter	Conditions	V _{CCI} (V)	V _{CCO} (V)	Min.	Max.	Units
I _{OFF}	Power Off Leakage	A_n , V_l or $V_O = 0V$ to 3.6V	0	3.6		±10.0	μA
	Current	B_n , V_l or $V_O = 0V$ to 3.6V	3.6	0		±10.0	
I _{OZ}	3-STATE Output	$A_n, B_n \qquad \overline{OE} = V_{IH}$	3.6	3.6		±10.0	μA
	Leakage ⁽⁵⁾ $0 \le V_{O} \le 3.6V$	B_n , $\overline{OE} = Don't Care$	0	3.6		+10.0	
	$V_{I} = V_{IH} \text{ or } V_{IL}$	A_n , $\overline{OE} = Don't Care$	3.6	0		+10.0	
I _{CCA/B}	Quiescent Supply Current ⁽⁶⁾	$V_I = V_{CCI}$ or GND; $I_O = 0$	1.1–3.6	1.1–3.6		20.0	μΑ
I _{CCZ}	Quiescent Supply Current ⁽⁶⁾	$V_I = V_{CCI}$ or GND; $I_O = 0$	1.1–3.6	1.1–3.6		20.0	μΑ
I _{CCA}	Quiescent Supply	$V_I = V_{CCA}$ or GND; $I_O = 0$	0	1.1–3.6		-10.0	μA
	Current	$V_I = V_{CCA}$ or GND; $I_O = 0$	1.1–3.6	0		10.0	μA
I _{CCB}	Quiescent Supply	$V_I = V_{CCB}$ or GND; $I_O = 0$	1.1–3.6	0		-10.0	μΑ
	Current	$V_I = V_{CCB}$ or GND; $I_O = 0$	0	1.1–3.6		10.0	μA
$\Delta I_{CCA/B}$	Increase in I _{CC} per Input; Other Inputs at V _{CC} or GND	V _{IH} = 3.0	3.6	3.6		500	μΑ

DC Electrical Characteristics (Continued)

Notes:

3. V_{CCI} = the V_{CC} associated with the data input under test.

4. V_{CCO} = the V_{CC} associated with the output under test.

5. Don't Care = Any valid logic level.

6. Reflects current per supply, $V_{CCA} \text{ or } V_{CCB}.$

AC Electrical Characteristics

$V_{CCA} = 3.0V$ to 3.6V

					T _A	= -40 °C	C to +85	5°C				
			c _B = V _{CC} o 3.6V 2.3V to			V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	
t _{PZH} , t _{PZL}	Output Enable \overline{OE} to B	0.5	4.0	0.7	4.4	1.0	5.9	1.0	6.4	1.5	17.0	ns
	Output Enable OE to A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	3.8	0.2	4.0	0.7	4.8	1.5	6.2	2.0	17.0	ns
	Output Disable OE to A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	

$V_{\mbox{\scriptsize CCA}}=2.3V$ to 2.7V

					T _A	= -40 °C	C to +85	5°C				
		V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	ns
	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	
t _{PZH} , t _{PZL}	Output Enable OE to B	0.6	4.2	0.8	4.6	1.0	6.0	1.0	6.8	1.5	17.0	ns
	Output Enable OE to A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.2	4.1	0.2	4.3	0.7	4.8	1.5	6.7	2.0	17.0	ns
	Output Disable OE to A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	

V_{CCA} = 1.65V to 1.95V

					T _A	= -40 °C	C to +85	õ°C				
		V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	ns
	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	Í l
t _{PZH} , t _{PZL}	Output Enable \overline{OE} to B	0.6	5.2	0.8	5.4	1.2	6.9	1.2	7.2	1.5	18.0	ns
	Output Enable \overline{OE} to A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	Í l
t _{PHZ} , t _{PLZ}	Output Disable \overline{OE} to B	0.2	5.1	0.2	5.2	0.8	5.2	1.5	7.0	2.0	17.0	ns
	Output Disable \overline{OE} to A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	

AC Electrical Characteristics (Continued)

$V_{CCA} = 1.4V \text{ to } 1.6V$

					T _A	= -40 °C	C to +85	5°C				
		V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	ns
	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	ĺ
t _{PZH} , t _{PZL}	Output Enable OE to B	1.1	7.5	1.1	7.6	1.3	7.7	1.4	7.9	2.0	20.0	ns
	Output Enable OE to A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	ĺ
t _{PHZ} , t _{PLZ}	Output Disable OE to B	0.4	6.1	0.4	6.2	0.9	6.2	1.5	7.5	2.0	18.0	ns
	Output Disable OE to A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	

$V_{CCA} = 1.1V$ to 1.3V

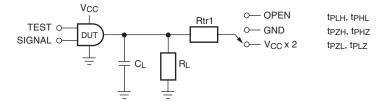
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$										
			св ⁼ о 3.6V		св ⁼ o 2.7V	1.65	св = V to 5V	V _{CC} 1.4V t	св = о 1.6V		с _в = о 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	ns
	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	
t _{PZH} , t _{PZL}	Output Enable OE to B	1.0	12.0	1.0	9.0	2.0	10.0	2.0	11.0	2.0	24.0	ns
	Output Enable OE to A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	
t _{PHZ} , t _{PLZ}	Output Disable \overline{OE} to B	1.0	15.0	0.7	7.0	1.0	8.0	2.0	10.0	2.0	20.0	ns
	Output Disable \overline{OE} to A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	

Capacitance

			$T_A = +25^{\circ}C$	
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance Control Pins (OE, T/Rn)	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0$ V or $V_{CCA/B}$	4.0	pF
C _{I/O}	Input/Output Capacitance An, Bn Ports	$V_{CCA} = V_{CCB} = 3.3V$, $V_I = 0V$ or $V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	$\label{eq:V_CCA} \begin{split} V_{CCA} = V_{CCB} = 3.3 \text{V}, \ V_I = 0 \text{V or } V_{CC}, \\ F = 10 \text{MHz} \end{split}$	20.0	pF

3-STATE Outputs and Independent Direction Controls FXL2TD245 Low Voltage Dual Supply 2-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and

AC Loading and Waveforms

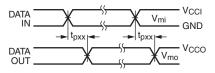


Test	Switch
t _{PLH} , t _{PHL}	OPEN
t _{PLZ} , t _{PZL}	$ \begin{array}{l} V_{CCO} \mbox{ x } 2 \mbox{ at } V_{CCO} = 3.3 \pm 0.3 \mbox{V}, 2.5 \mbox{V} \pm 0.2 \mbox{V}, \\ 1.8 \mbox{V} \pm 0.15 \mbox{V}, 1.5 \mbox{V} \pm 0.1 \mbox{V}, 1.2 \mbox{V} \pm 0.1 \mbox{V} \end{array} $
t _{PHZ} , t _{PZH}	GND



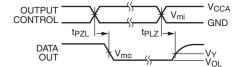
AC Load Table

V _{CCO}	CL	RL	Rtr1
1.2V ± 0.1V	15pF	2kΩ	2kΩ
1.5V ± 0.1V	15pF	2kΩ	2kΩ
1.8V ± 0.15V	15pF	2kΩ	2kΩ
$2.5V\pm0.2V$	15pF	2kΩ	2kΩ
$3.3V \pm 0.3V$	15pF	2kΩ	2kΩ



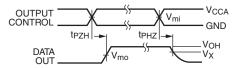
Input $t_R=t_F=2.0$ ns, 10% to 90% Input $t_R=t_F=2.5 \text{ns},$ 10% to 90%, @ V_I=3.0V to 3.6V only

Figure 2. Waveform for Inverting and Non-Inverting Functions



Input $t_R=t_F=2.0$ ns, 10% to 90% Input $t_R=t_F=2.5 \text{ns},$ 10% to 90%, @ V_I=3.0V to 3.6V only

Figure 3. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic



Input $t_R = t_F = 2.0$ ns, 10% to 90%

Input $t_R = t_F = 2.5$ ns, 10% to 90%, @ V_I = 3.0V to 3.6V only

Figure 4. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

	V _{cc}							
Symbol	$\textbf{3.3V} \pm \textbf{0.3V}$	$\textbf{2.5V} \pm \textbf{0.2V}$	$\textbf{1.8V} \pm \textbf{0.15V}$	$1.5V\pm0.1V$	$\textbf{1.2V} \pm \textbf{0.1V}$			
V _{mi}	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2			
V _{mo}	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2			
V _X	V _{OH} -0.3V	V _{OH} -0.15V	V _{OH} -0.15V	V _{OH} -0.1V	V _{OH} -0.1V			
V _Y	V _{OL} +0.3V	V _{OL} +0.15V	V _{OL} +0.15V	V _{OL} +0.1V	V _{OL} +0.1V			

For V_{mi} : $V_{CCI} = V_{CCA}$ for Control Pins T/ \overline{R} and \overline{OE} , or $V_{CCA}/2$

3-STATE Outputs and Independent Direction Controls

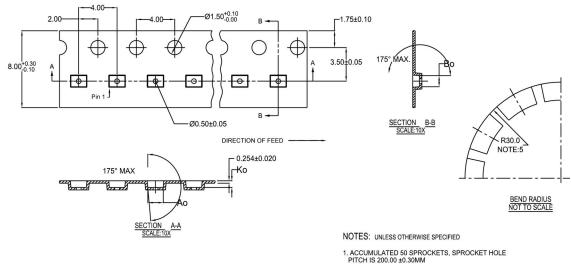
FXL2TD245 Low Voltage Dual Supply 2-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and

Tape and Reel Specification

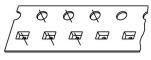
Tape Format for MicroPak 10

Package Designator	Tape Section	Number Cavities	Cavity Status	Cover Tape Status
L10X	Leader (Start End)	125 (typ)	Empty	Sealed
	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

Tape Dimensions inches (millimeters)



10	300056	2.30±0.05	1.78±0.05	0.68±0.05
8	300038	1.78±0.05	1.78±0.05	0.68 ± 0.05
6	300033	1.60 ± 0.05	1.15 ± 0.05	0.70 ± 0.05



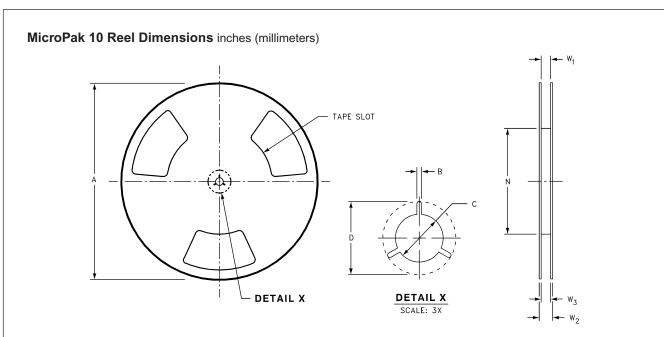
SCALE: 6X

2. NO INDICATED CORNER RADIUS IS 0.127MM

3. CAMBER NOT TO EXCEED 1MM IN 100MM

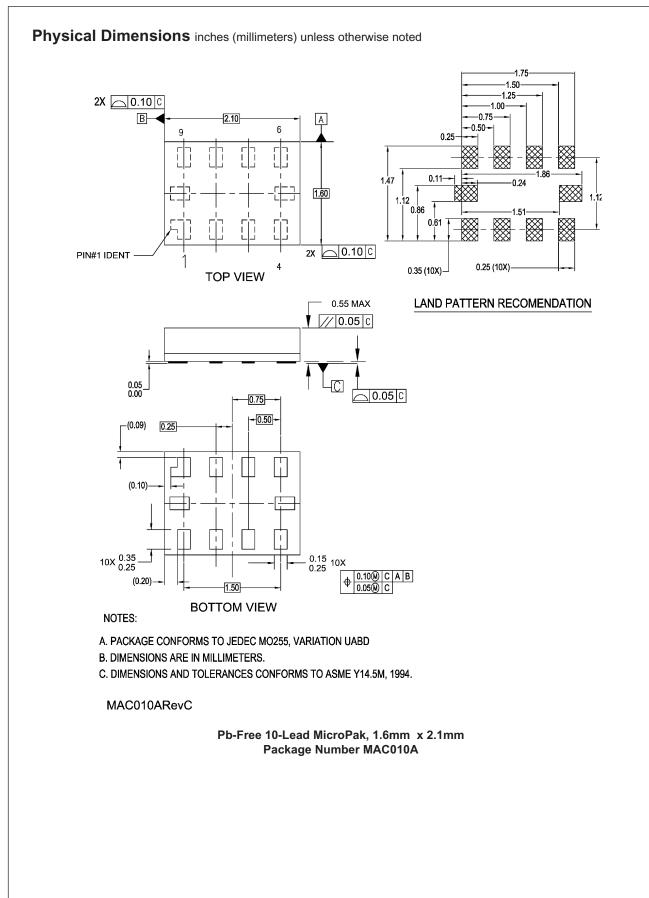
4. SMALLEST ALLOWABLE BENDING RADIUS

5. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE **3-STATE** FXL2TD245 **Outputs and Independent Direction Controls** Low Voltage Dual Supply 2-Bit Signal Translator with Configurable Voltage Supplies and Signal Levels and



Tape Size	Α	в	С	D	N	W1	W2	W3
8 mm	7.0	0.059	0.512	0.795	2.165	0.331 + 0.059/-0.000	0.567	W1 + 0.078/-0.039W
	(177.8)	(1.50)	(13.00)	(20.20)	(55.00)	(8.40 + 1.50/-0.00)	(14.40)	(W1 + 2.00/-1.00)





3-STATE Outputs and Independent Direction Controls



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